

BRCS040N03DP

Rev.A Dec. -2021

/ Descriptions

TO-252 N MOS

N-CHANNEL MOSFET in a TO-252 Plastic Package.

/ Features

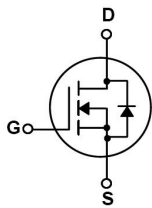
Low gate charge, low crss, fast switching, HF Product.

/ Applications

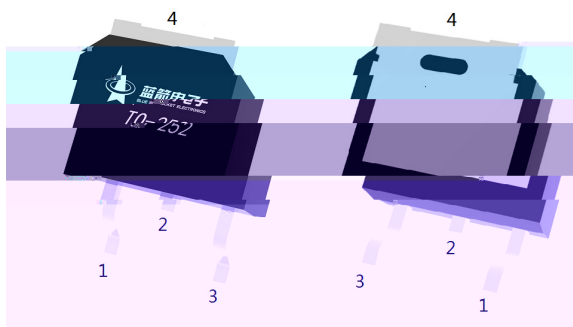
DC/DC

These devices are well suited for high efficiency switching DC/DC converters and switch mode power supplies.

/ Equivalent Circuit



/ Pinning



PIN1 G

PIN 2 D

PIN 3 S

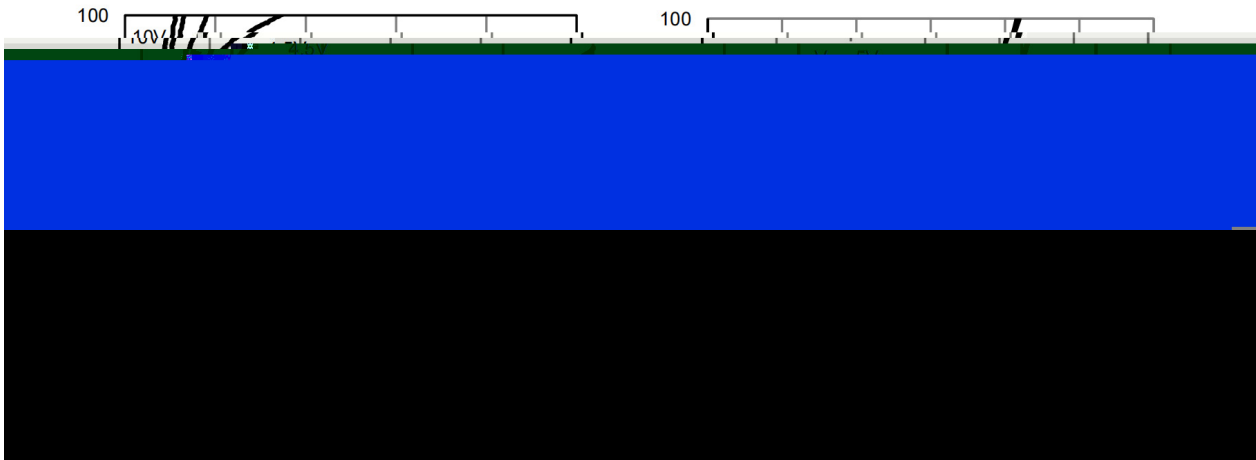
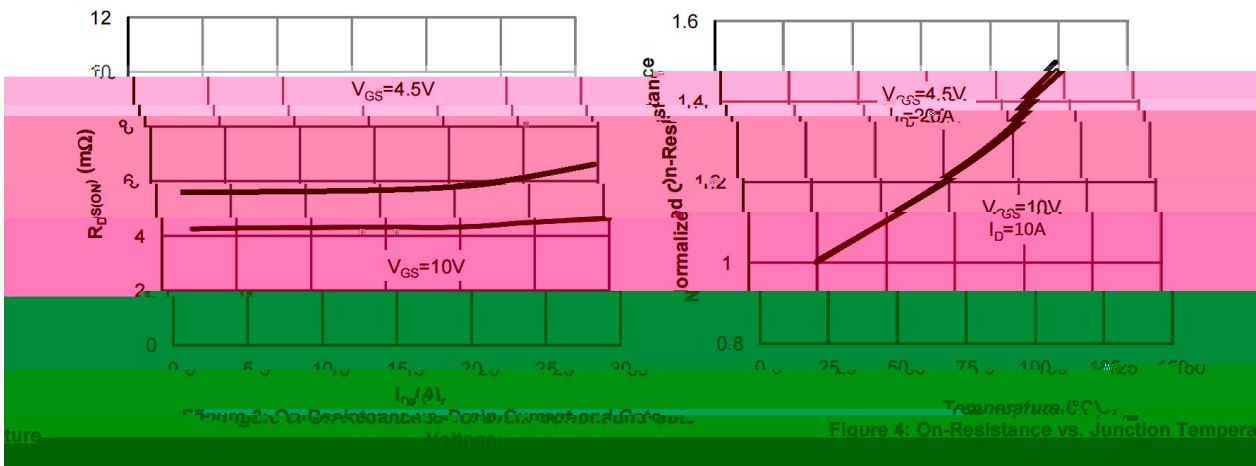
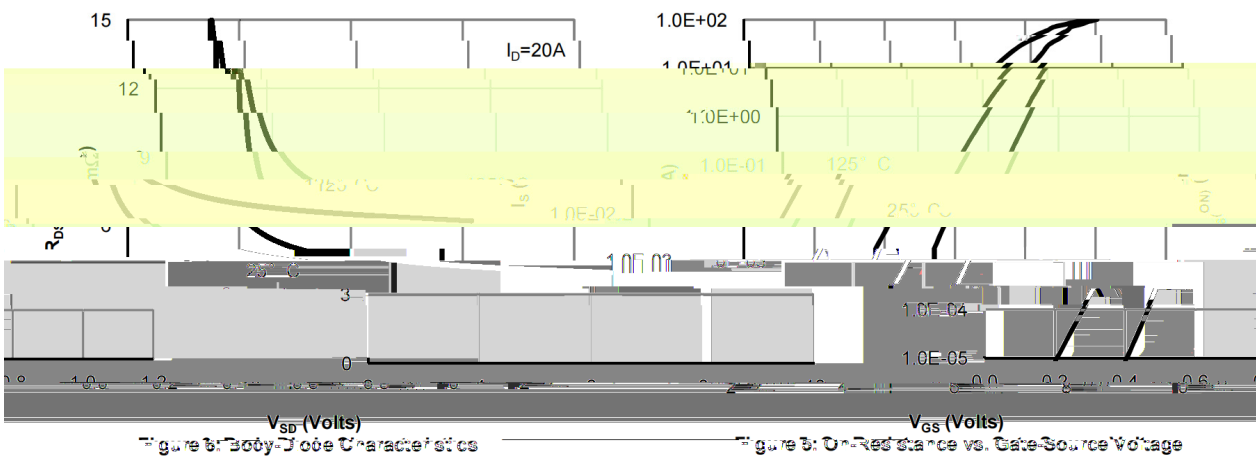
PIN 4 D

/ Marking

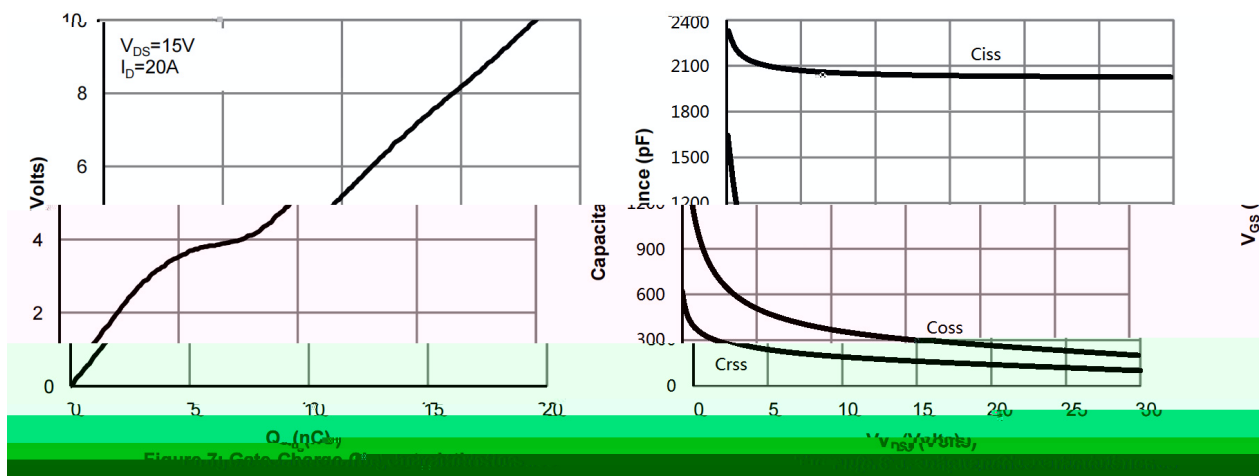
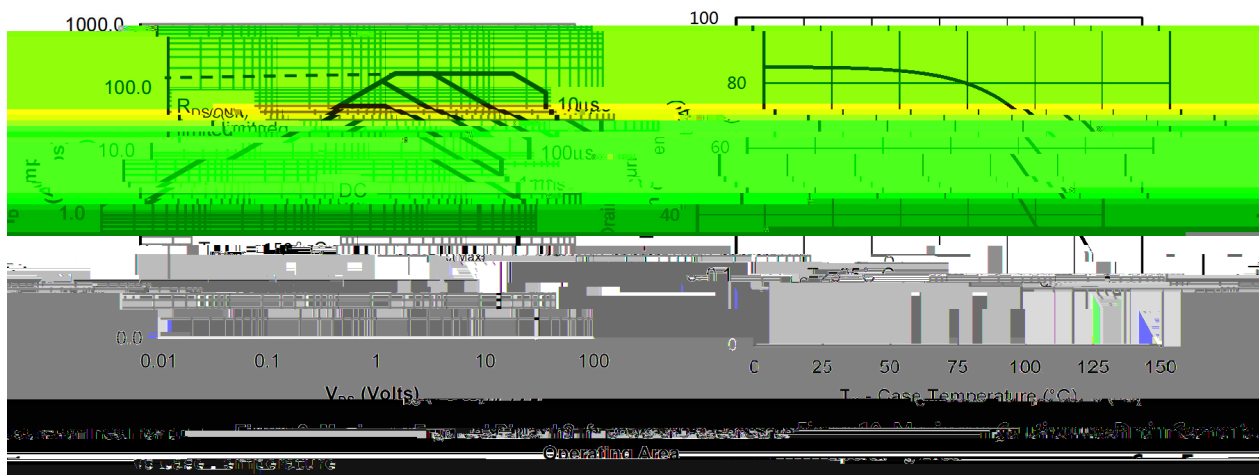
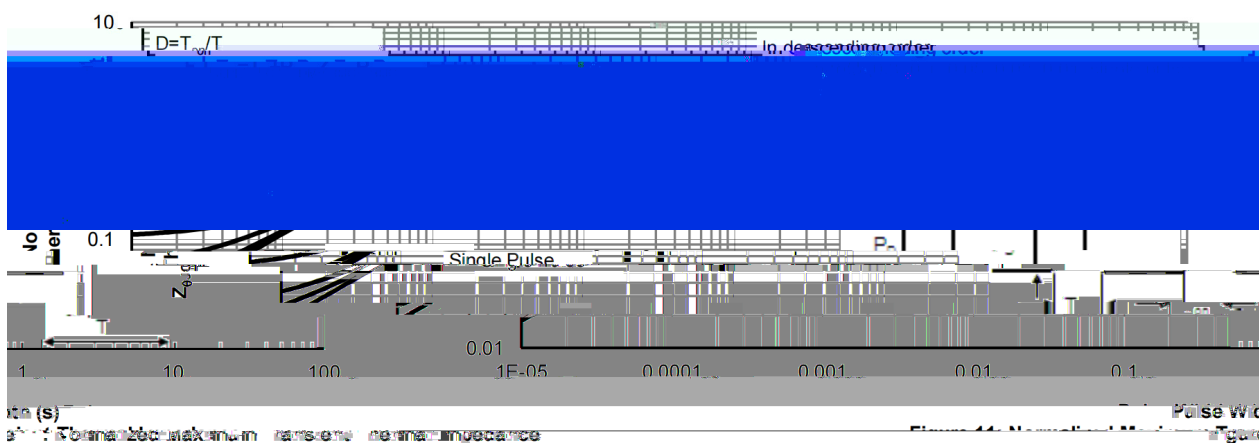
See Marking Instructions.

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	30	V
Drain Current	$I_D(T_c=25^\circ\text{C})$	85	A
Peak Drain Current	I_{DM}	280	A
Gate-Source Voltage	V_{GS}	20	V
Avalanche Current	I_{AS}	26	A
Single Pulsed Avalanche Energy	E_{AS}	354	mJ
Total Power Dissipation	$P_D(T_c=25^\circ\text{C})$	100	W
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	$^\circ\text{C}$
Thermal resistance, junction to ambient $t \leq 10\text{s}$	$R_{\theta JA}$	20	$^\circ\text{C/W}$

/ Electrical Characteristic Curve

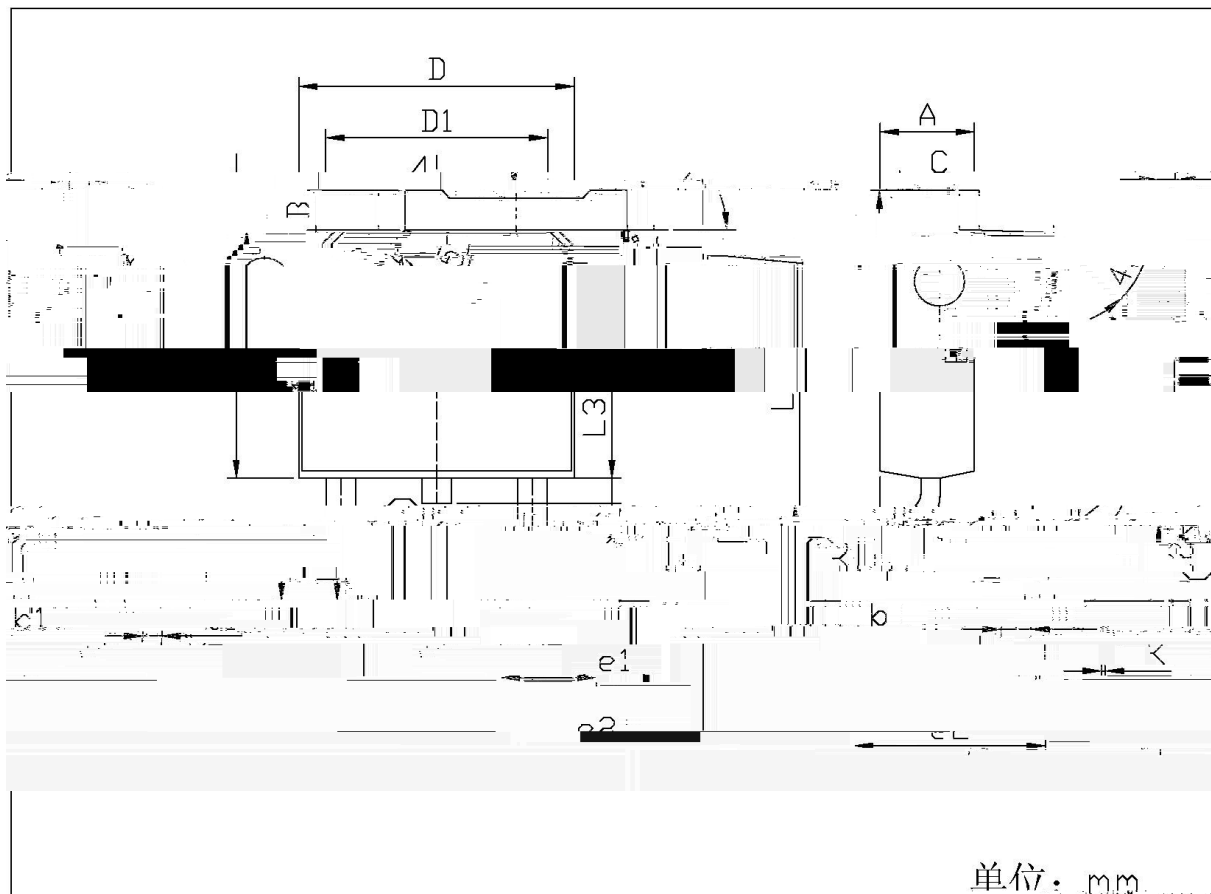


Electrical Characteristic Curve



/ Package Dimensions

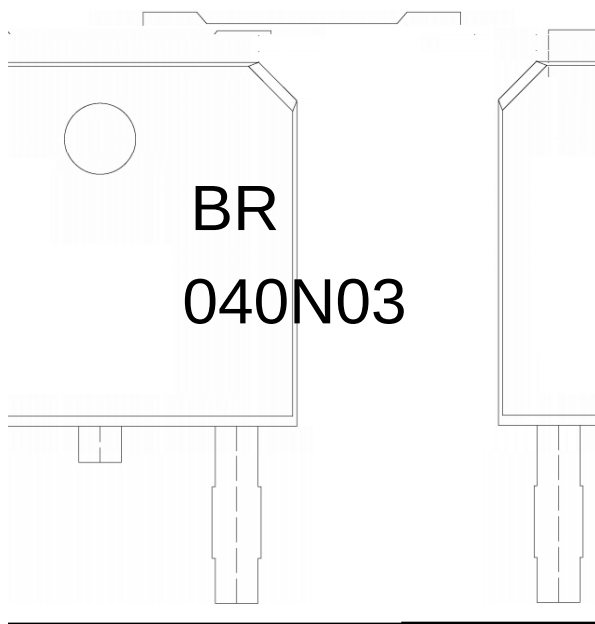
TO-252#

[illegible]

TI-252



/ Marking Instructions



BR

040N03

Note:

BR: Company Code

040N03: Product Type

****: Lot No. Code, code change with Lot No


() / Temperature Profile for IR Reflow Soldering(Pb-Free)

Note:

- | | | | |
|---|---------|-----------|---|
| 1 | 150 180 | 60 90sec; | 1.Preheating:150~180 , Time:60~90sec. |
| 2 | 245±5 | 5±0.5sec; | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | 2 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260±5	10±1 sec.	Temp.:260±5	Time:10±1 sec
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/ Packaging SPEC.

/ REEL

Package Type	Units	Dimension	(unit mm ³)
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